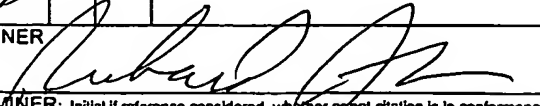


FORM PTO-1449 (REV. 7-80)		U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE		ATTY. DOCKET NO. NIT-337-02	SERIAL NO.		
LIST OF DOCUMENTS CITED BY APPLICANT <i>(Use several sheets if necessary)</i>				APPLICANT K. MOCHIZUKI et al			
				FILING DATE 1/5/04		GROUP 2813	
U.S. PATENT DOCUMENTS							
* EXAMINER INITIAL	DOCUMENT	DATE	NAME	CLASS	SUBCLASS	FILING DATE (If Appropriate)	
RB	AA	5,449,930	09/1995	Zhou, Guo-Gang	<u> </u>	<u> </u>	
	AB	5,512,496	04/1996	Chau et al	<u> </u>	<u> </u>	
	AC	5,233,219	08/1993	Shimoji et al	<u> </u>	<u> </u>	
	AD	6,133,594	10/2000	Iwai et al	<u> </u>	<u> </u>	
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						
FOREIGN PATENT DOCUMENTS							
	DOCUMENT	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
						YES	NO
	AL					<input type="checkbox"/>	<input type="checkbox"/>
	AM					<input type="checkbox"/>	<input type="checkbox"/>
	AN					<input type="checkbox"/>	<input type="checkbox"/>
	AO					<input type="checkbox"/>	<input type="checkbox"/>
	AP					<input type="checkbox"/>	<input type="checkbox"/>
OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)							
RB	AR	"Heterojunction bipolar transistors of InGaAs system for microwave power amplifier", OYO-BUTURI, Vol. 66, No. 2, (1997), pp. 156-160.					
RB	AS	Journal of Vacuum Science and Technology, Vol. 18, No. 2, 2000, pp. 761-764.					
RB	AT	IEEE Electron Device Letters, Vol. 21, No. 9, 2000, pp. 427-429.					
EXAMINER 				DATE CONSIDERED 09/01/05			

* EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.